

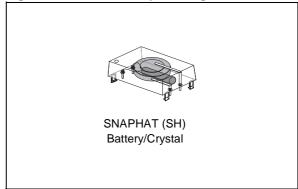
M4T28-BR12SH M4T32-BR12SH

TIMEKEEPER® SNAPHAT® (Battery & Crystal)

FEATURES SUMMARY

- PROVIDES BATTERY BACKUP POWER FOR NON-VOLATILE TIMEKEEPER® and SUPERVISOR DEVICES IN THE 28- OR 44-PIN SNAPHAT SOIC PACKAGE
- REMOVABLE BATTERY AVOIDS HEAT ASSOCIATED WITH SURFACE MOUNT PROCESS
- SNAPS DIRECTLY ONTO SURFACE-MOUNTED SNAPHAT SOIC
- CHOICE OF BATTERY CAPACITIES:
 - M4T28-BR12SH = 48mAh
 - M4T32-BR12SH = 120mAh
- KEYED INSERTION TO INSURE PROPER ASSEMBLY
- REMOVABLE FOR REPLACEMENT and PROPER DISPOSAL
- AVAILABLE IN TUBES OR TAPE & REEL





January 2002 1/12

M4T28-BR12SH, M4T32-BR12SH

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SUMMARY DESCRIPTION

The M4TXX-BR12SH SNAPHAT® top is a detachable lithium power source for ST's non-volatile TIMEKEEPER® surface-mount SOIC (MH) package (28- and 44-pin).

The SNAPHAT top contains both the battery and crystal and is designed to be "snapped on" after the SOIC is surface mounted on the PC board. Thus the two piece solution prevents the battery and crystal from being exposed to the high temperatures of the surface mount process.

Figure 2. Logic Diagram

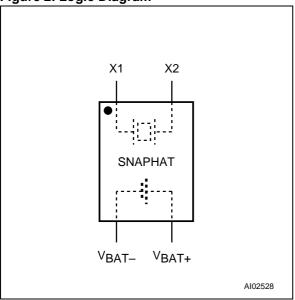


Table 1. Signal Names

X1	Crystal Input		
X2	Crystal Output		
V_{BAT-}	Negative Voltage		
V _{BAT+}	Positive Voltage		

MAXIMUM RATING

Stressing the device above the rating listed in the "Absolute Maximum Ratings" table may cause permanent damage to the device. These are stress ratings only and operation of the device at these or any other conditions above those indicated in the Operating sections of this specification is

not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability. Refer also to the STMicroelectronics SURE Program and other relevant quality documents.

Table 2. Absolute Maximum Ratings

Symbol	Parameter	Value	Unit	
т	And in all On and in a Transport	Grade 1	0 to 70	°C
T _A	Ambient Operating Temperature	Grade 6 ⁽¹⁾	-40 to 85	°C
T _{STG}	Storage Temperature (V _{CC} Off, Oscillator Off)	-40 to 85	°C	

Note: 1. Only the M4T32-BR12SH is available in Industrial temperature (Grade 6).

CAUTION: Do NOT wave solder SOIC to avoid damaging SNAPHAT sockets.

DC AND AC PARAMETERS

This section summarizes the operating and measurement conditions, as well as the DC and AC characteristics of the device. The parameters in the following DC and AC Characteristic tables are derived from tests performed under the Measure-

ment Conditions listed in the relevant tables. Designers should check that the operating conditions in their projects match the measurement conditions when using the quoted parameters.

Table 3. Operating and AC Measurement Conditions

Parameter	M4T28-BR12SH	M4T32-BR12SH	Unit
Nominal Battery Voltage (V _{CC})	2.8	2.8	V
Nominal Battery Capacity	48	120	mAh
Battery Chemistry	Li(CF)	Li(CF)	
Crystal Load Capacitance (C _L)	12.5	12.5	pF
Nominal Crystal Frequency	32.768	32.768	kHz
Crystal Accuracy (@ 25°C)	± 35	± 35	ppm

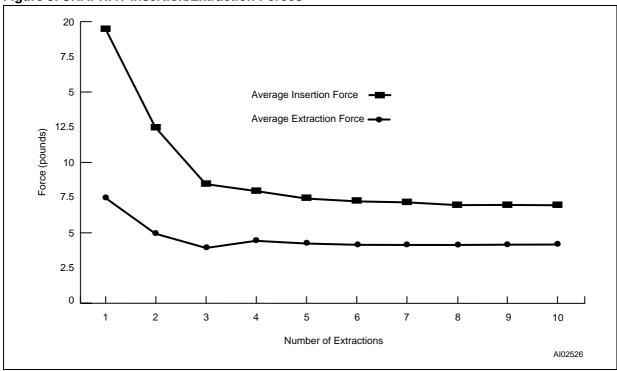
MECHANICAL INFORMATION

Electrical connection to the SOIC is made through four pins that connect to the four press fitted sockets at each end of the SOIC. Critical contact points between the pins and sockets are gold-plated to resist oxidation. Internally, each socket contains six independent contact fingers to form redundant connections between the two components. These sockets were designed with high point contact force to provide the lowest possible contact resistance. The SNAPHAT® top also incorporates four molded-in retaining clips which hold onto the ends of the SOIC insuring mechanical and electrical connection even under severe mechanical shock and vibration. The combined SOIC and SNAPHAT

assembly can sustain shock levels in excess of 100 g without separating. This package also passes variable frequency testing in accordance with MIL-STD-883, method 2007.2, condition A.

Figure 3 illustrates the affect of repeated insertion and extraction of the SNAPHAT top to the SOIC. The force required to extract the SNAPHAT, and then to re-insert it, reduces each time. After three or four extractions, though, the reduction starts to become unnoticeable, and the force required remains at a fairly constant figure. Typically, though, the SNAPHAT will only need to be extracted and re-inserted once in its lifetime.





Battery Characteristics

Figure 4, page 7 illustrates the lithium coin cell discharge rate for a given load. This demonstrates the characteristically flat voltage level supplied by the battery until very near the end of its life. These discharge levels have been greatly accelerated in comparison to the normal, actual usage.

Note: These batteries contain no Mercury (Hg), Cadmium (Cd), or Lead (Pb).

UL Recognition

The M4Txx-BR12SH has been recognized by Underwriters Laboratories under their Component Recognition Program and carries U.L. File Number E89556.

Battery Life

For information on Data Retention Life and Battery Storage Life, please refer to the Application Note AN1012.

General Notes

ST has conducted experiments using a manual press which determined that if approximately 60

pounds of force is applied to the top of the SNAPHAT®, battery damage and/or die cracks could be induced. As Figure 3, page 5 specifies, only an average of 20 force-pounds is required for proper insertion. We recommend that no more than 40 pounds of force be applied during SNAPHAT insertion.

If a manual press in employed, it is very important that it be calibrated such that it cannot exceed this limit

To remove the SNAPHAT top for replacement, a DIP/IC extractor tool should be used (see Figure 5). The SNAPHAP top should be grabbed by the narrow end to avoid bending the pins.

Caution: To avoid draining battery do NOT place SNAPHAT pins into conductive foam.

Caution: To avoid damaging SNAPHAT sockets do NOT wave solder SOIC.

For battery disposal information, see on the web at www.rayovac.com.

Figure 4. Battery Discharge Rates

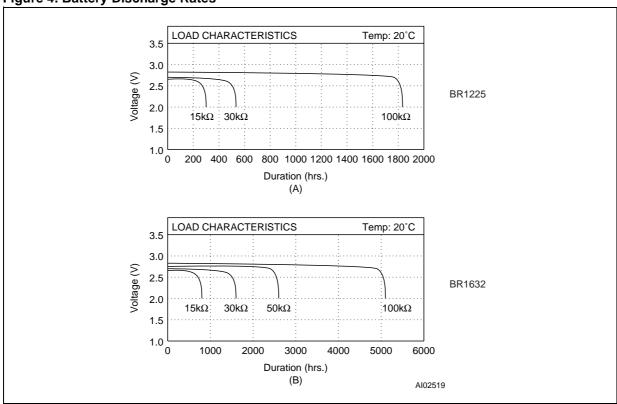
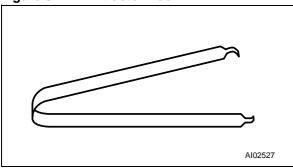
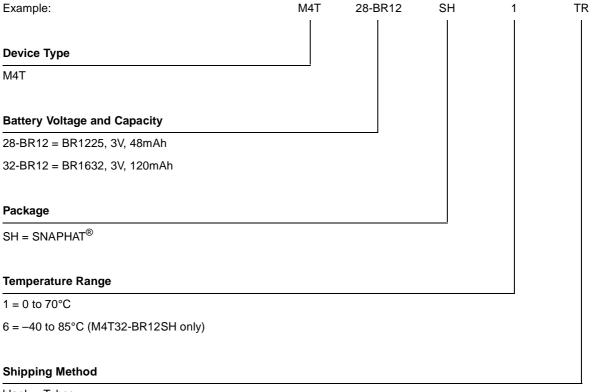


Figure 5. DIP Extractor Tool



PART NUMBERING

Table 4. Ordering Information Scheme



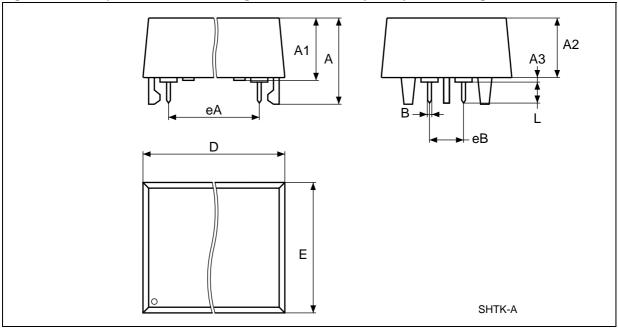
blank = Tubes

TR = Tape & Reel

For a list of available options (e.g., Speed, Package) or for further information on any aspect of this device, please contact the ST Sales Office nearest to you.

PACKAGE MECHANICAL INFORMATION

Figure 6. SH – 4-pin SNAPHAT Housing for 48mAh Battery & Crystal, Package Outline



Note: Drawing is not to scale.

Table 5. SH – 4-pin SNAPHAT Housing for 48mAh Battery & Crystal, Package Mechanical Data

Symb		mm			inches	
Symb	Тур	Min	Max	Тур	Min	Max
А			9.78			0.385
A1		6.73	7.24		0.265	0.285
A2		6.48	6.99		0.255	0.275
A3			0.38			0.015
В		0.46	0.56		0.018	0.022
D		21.21	21.84		0.835	0.860
E		14.22	14.99		0.560	0.590
eA		15.55	15.95		0.612	0.628
eB		3.20	3.61		0.126	0.142
L		2.03	2.29		0.080	0.090

A1 A A3 A2

eA B E SHTK-A

Figure 7. SH – 4-pin SNAPHAT Housing for 120mAh Battery & Crystal, Package Outline

Note: Drawing is not to scale.

Table 6. SH – 4-pin SNAPHAT Housing for 120mAh Battery & Crystal, Package Mechanical Data

Cumb		mm			inches	
Symb	Тур	Min	Max	Тур	Min	Max
Α			10.54			0.415
A1		8.00	8.51		0.315	0.335
A2		7.24	8.00		0.285	0.315
А3			0.38			0.015
В		0.46	0.56		0.018	0.022
D		21.21	21.84		0.835	0.860
E		17.27	18.03		0.680	0.710
eA		15.55	15.95		0.612	0.628
eB		3.20	3.61		0.126	0.142
L		2.03	2.29		0.080	0.090

REVISION HISTORY

Table 7. Document Revision History

Date	Revision Details			
November 1999	First Issue			
03/01/01	Reformatted			
06/04/01	Basic textual changes from reformatting activity			
07/10/01	Changes references to "SUPERVISOR" from "Controller;" clarify temperature characteristics			
01/21/02	Change to include Crystal Accuracy (Table 3); add text for SNAPHAT insertion force tolerance and battery characteristics note			

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